



SCOMES



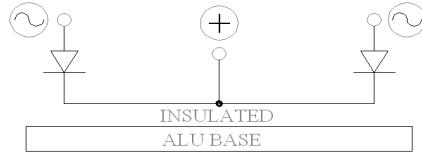
MCF160.04 IS

Insulated Version

FAST RECOVERY DIODE MODULE

Output Current **160 A**

Blocking Voltage **400 V**



| V _{RRM} [V] | V _{RSM} [V] | V _{OUT} [V] | P/N |
|-------------------------|-------------------------|-------------------------|-------------|
| 400 | 500 | 125 | MCF160.04IS |
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Features

Short recovery time
Low switching losses
Soft recovery behavior
Electrically insulated case

Applications

Antiparallel diode for high frequency switching devices
Free-wheeling diode in converters or motor controllers
Uninterruptible power supplies (UPS)
Ultrasonic cleaners and welders

| Diodes characteristics | | Conditions | T _j [°C] | Value |
|------------------------|---------------------------------------|-----------------------------------|---------------------|-----------------------|
| I _{F(AV)} | Average forward current | T _c = 70 °C | | 80 A |
| I _{FRM} | Repetitive forward current, max | Square wave, 20 kHz | | 160 A |
| I _{RRM} | Max repetitive peak reverse current | V = V _{RRM} | 150 | 2 mA |
| V _{F(TO)} | Threshold voltage | | 150 | 0,92 V |
| r _F | Forward slope resistance | | 150 | 1,8 mΩ |
| V _{FM} | Peak forward voltage, max | I _F = 80 A | 150 | 1,15 V |
| I _{FSM} | Surge forward current | Half sine wave, 10 ms | 25 | 800 A |
| I ² t | Max I ² t for fusing | | 25 | 3200 A ² s |
| C _T | Junction capacitance, typ | V = 200 V | 25 | 50 pF |
| Q _{rr} | Reverse recovery charge, typ | I _F = 80 A | | 1300 nC |
| I _{rr} | Reverse recovery current, typ | V _R = 200 V | 125 | 17 A |
| t _{rr} | Reverse recovery time, typ | dI _F / dt = 200 A / μs | | 150 ns |
| T _{jmax} | Operating junction temperature | | | -40 / 150 °C |
| R _{th(j-c)} | Thermal resistance (junction to case) | | | 0,83 °C/W |

| Module characteristics | | Conditions | Value |
|------------------------|--|---|------------|
| I _{OUT} | Output current (center tap connection) | T _c = 70 °C | 160 A |
| V _{INS} | RMS Insulating voltage | 50 / 60 Hz t = 1 s (i < 1 mA) | 3600 V |
| V _{INS} | RMS Insulating voltage | 50 / 60 Hz t = 60 s (i < 1 mA) | 3000 V |
| R _{th(c-h)} | Thermal resistance (case to heatsink) | Mounting surface flat, smooth and greased | 0,100 °C/W |
| T _{stg} | Max storage temperature | | 150 °C |
| W | Weight | | 115 g |
| M ₁ | Mounting torque, ± 15 % | | 5,5 N·m |
| | | | 48 lb·inch |
| M ₂ | Terminal connection torque, ± 15 % | | 4,0 N·m |
| | | | 35 lb·inch |

